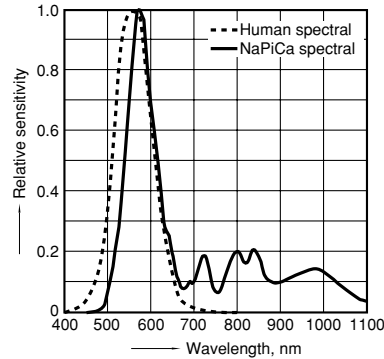


FEATURES

1. Built-in optical filter for spectral response similar to that of the human eye.

Peak sensitivity wavelength is 580 nm



2. Photocurrent is proportional to illumination. (linear output)

High photocurrent is achieved by built-in photocurrent amp.

$I_L = 260 \mu A$ (typical)

$E_v = 100 \text{ lx}$ (fluorescent light)

3. Uses environmentally friendly silicon chips.

4. Lead-free.

5. Operates on 1.5 to 6 V DC, which is suitable for battery operation.

6. Compact, SMD package

TYPICAL APPLICATIONS

1. Brightness detection for LCD backlight control for LCD devices (mobile phones, LCD TVs, car navigation systems, mobile PCs, and PDAs).

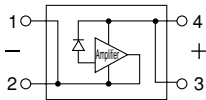
2. Brightness detection for circuits in household lighting, crime prevention lighting, and automatic lighting for bicycle.

3. Brightness detection for controlling the keypad backlight in mobile phones.

4. Brightness detection for surveillance cameras (night switching).



L 2.0mm .079inch
W 3.2mm .126inch
H 1.0mm .039inch



TYPES

Packing quantity: 3,000pcs.

Output rating	Part No.	
	Picked from the 1/4-pin side	Picked from the 2/3-pin side
260 μA *	AMS104Y	AMS104W

Note: $E_v = 100 \text{ lx}$ (Fluorescent lamp is used as light source)
Tape package is the standard packing style.

Ratings

1. Absolute maximum ratings (Ambient temperature: 25°C 77°F)

Item	Symbol	AMS104	Remarks
Reverse voltage	V_R	-0.5 to 8 V	
Photocurrent	I_L	5 mA	
Power dissipation	P	40 mW	
Operating temperature	T_{opr}	-30 to +85°C -22 to +185°F	Non-condensing at low temperatures
Storage temperature	T_{stg}	-40 to +100°C -40 to +176°F	Non-condensing at low temperatures

2. Recommended operating condition

Item	Symbol	AMS104	Remarks
Reverse voltage	Minimum	1.5 V	—
	Maximum	6 V	

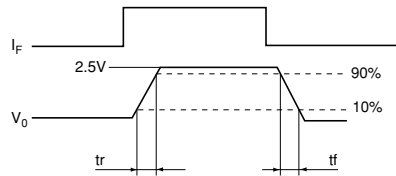
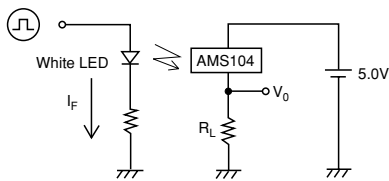
3. Electrical characteristics (Ambient temperature: 25°C 77°F)

Item	Symbol	AMS104	Condition	
Peak sensitivity wavelength	λ_p	580 nm	—	
Photocurrent 1	Minimum	9.1 μA	$V_R = 5\text{ V}$ $E_v = 5\text{ lx}^{*1}$	
	Typical	13 μA		
	Maximum	16.9 μA		
Photocurrent 2	Minimum	182 μA	$V_R = 5\text{ V}$ $E_v = 100\text{ lx}^{*1}$	
	Typical	260 μA		
	Maximum	338 μA		
Photocurrent 3	Typical	500 μA	$V_R = 5\text{ V}$ $E_v = 100\text{ lx}^{*2}$	
Dark current	Maximum	0.3 μA	$V_R = 5\text{ V}$	
Switching time	Rise time	Typical	8.5 ms	$V_R = 2.5\text{ V}$, $V_o = 2.5\text{ V}$ $R_L = 5\text{ k}\Omega$
	Fall time	Typical	8.5 ms	

*1 Fluorescent lamp is used as light source.

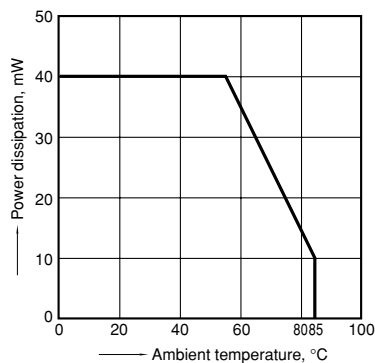
*2 CIE standard illuminant 'A' is used as light source.

*3 Measuring method for switching time.



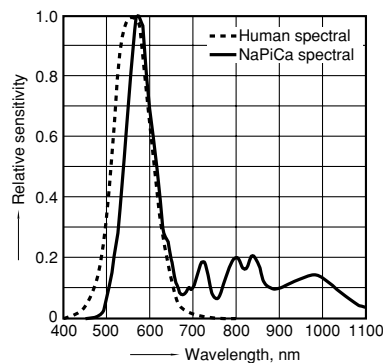
REFERENCE DATA

1. Power dissipation vs. ambient temperature characteristics



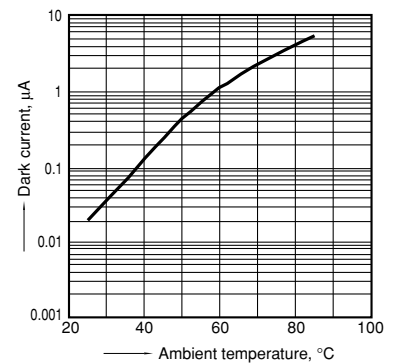
2. Relative sensitivity vs. wavelength characteristics

Ambient temperature: 25°C 77°F



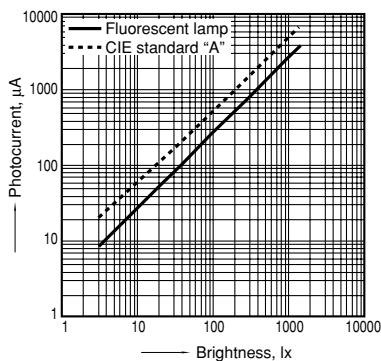
3. Dark current vs. ambient temperature characteristics

Reverse voltage: 5V



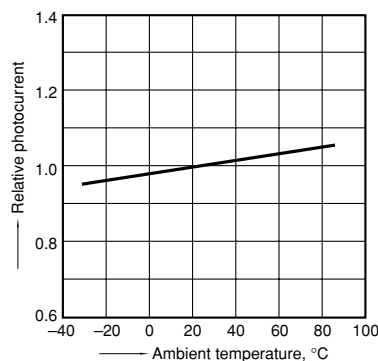
4. Photocurrent vs. brightness characteristics

Light source: Fluorescent lamp, CIE standard "A"
Reverse voltage: 5V, Ambient temperature: 25°C 77°F



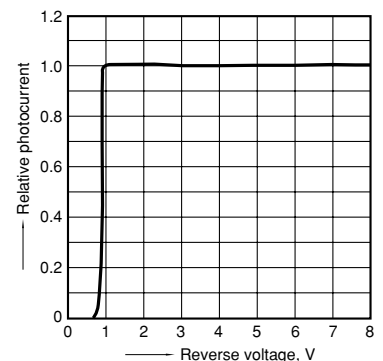
5. Relative photocurrent vs. ambient temperature characteristics

Light source: Fluorescent lamp, Brightness: 100 lx
Reverse voltage: 5V



6. Relative photocurrent vs. reverse voltage characteristics

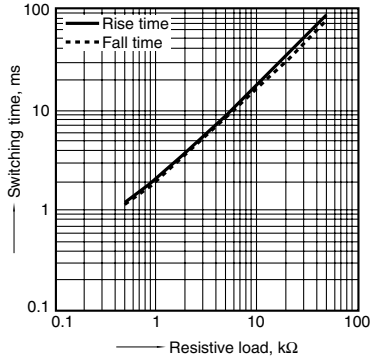
Light source: Fluorescent lamp, Brightness: 100 lx
Ambient temperature: 25°C 77°F



Light Sensor (AMS1)

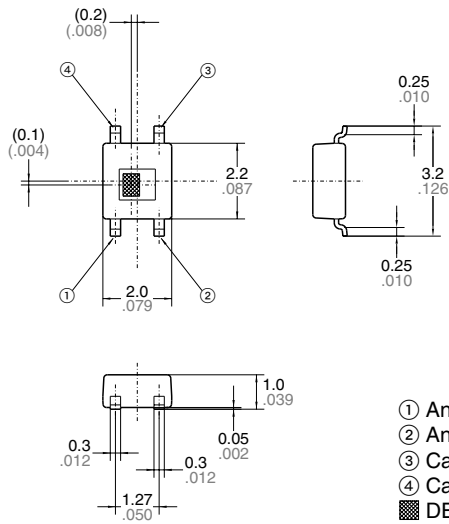
7. Switching time vs. resistive load characteristics

Light source: White LED, Reverse voltage: 5V
 Resistive load voltage: 2.5V
 Ambient temperature: 25°C 77°F

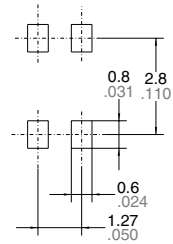


DIMENSIONS

mm inch



Recommended mounting pad (Top view)



Tolerance: $\pm 0.1 \pm .004$

- ① Anode
- ② Anode
- ③ Cathode
- ④ Cathode
- DETECTION AREA

Terminal thickness: $t=0.125$
 General Tolerance: $\pm 0.1 \pm .004$

CAUTIONS FOR USE

1. Applying stress that exceeds the absolute maximum rating

If the voltage or current value for any of the terminals exceeds the absolute maximum rating, internal elements will deteriorate because of the excessive voltage or current. In extreme cases, wiring may melt, or silicon P/N junctions may be destroyed.

As a result, the design should ensure that the absolute maximum ratings will never be exceeded, even momentarily.

2. Deterioration and destruction caused by discharge of static electricity

This phenomenon is generally called static electricity destruction, and occurs when static electricity generated by various factors is discharged while the relay terminals are in contact, producing internal destruction of the element. To prevent problems from static electricity, the following precautions and measures should be taken when using your device.

1) Employees handling sensor should wear anti-static clothing and should be grounded through protective resistance of 500 k Ω to 1 M Ω .

2) A conductive metal sheet should be placed over the work table. Measuring instruments and jigs should be grounded.

3) When using soldering irons, either use irons with low leakage current, or ground the tip of the soldering iron. (Use of low-voltage soldering irons is also recommended.)

4) Devices and equipment used in assembly should also be grounded.

5) When packing printed circuit boards and equipment, avoid using high-polymer materials such as foam styrene, plastic, and other materials which carry an electrostatic charge.

6) When storing or transporting sensor, the environment should not be conducive to generating static electricity (for instance, the humidity should be between 45 and 60%), and sensor should be protected using conductive packing materials.

3. When powered on, please note that current flow in the sensor will fluctuate for the purpose of internal circuit stability.

4. Storage

The sensors are compact, transparent, plastic packages. They are sensitive to moisture and come in sealed, moisture-proof packages. Observe the following cautions when storing.

1) After the moisture-proof package is unsealed, take the devices out of storage as soon as possible (within 1 week at the

most).

2) If the devices are to be left in storage for a considerable period after the moisture-proof package has been unsealed, it is recommended to keep them in another moisture-proof bag containing silica gel (within 3 months at the most).

3) Storage under extreme conditions will cause soldering degradation, external appearance defects, and deterioration of the characteristics. The following storage conditions are recommended:

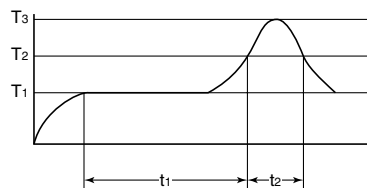
- Temperature: 0 to 30°C 32 to 86°F
- Humidity: Less than 60% R.H.
- Atmosphere: No harmful gasses such as sulfurous acid gas, minimal dust.

*When mounting with solder, if thermal stress is applied to sensors that have absorbed moisture, the moisture will vaporize, swelling will occur, and the inside of the package will become stressed. This may cause the package surface to blister or crack. Therefore, please take caution and observe the soldering conditions in the following section.

5. Recommended soldering conditions

1) Recommended condition 1: (Recommended solder composition: Sn3.0Ag0.5Cu) If using SnPb eutectic solder, please refer to "Recommended condition 2" in section 2), below.

(1) IR (Infrared reflow) soldering method



$T_1 = 155$ to 180°C 311 to 356°F

$T_2 = 230^\circ\text{C}$ 446°F

$T_3 = 250^\circ\text{C}$ 482°F or less

$t_1 = 60$ to 120 s or less

$t_2 = 30$ s or less

(2) Soldering iron method
Tip temperature: 350 to 400°C 662 to 752°F

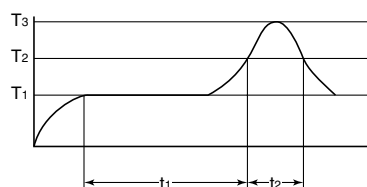
Wattage: 30 to 60 W

Soldering time: within 3 s

2) Recommended condition 2:

(Recommended solder composition: SnPb eutectic)

(1) IR (Infrared reflow) soldering method



$T_1 = 155$ to 165°C 311 to 329°F

$T_2 = 180$ to 200°C 356 to 392°F

$T_3 = 245^\circ\text{C}$ 473°F or less

$t_1 = 120$ s or less

$t_2 = 30$ s or less

(2) Soldering iron method

Tip temperature: 280 to 300°C 536 to 572°F

Wattage: 30 to 60 W

Soldering time: within 5 s

3) Do not do flow soldering.

6. Notes for mounting

1) If many different packages are combined on a single substrate, then lead temperature rise is highly dependent on package size. For this reason, please make sure that the temperature of the terminal solder area of the Light sensor falls within the temperature conditions of item 9 before mounting.

2) If the mounting conditions exceed the recommended solder conditions in item 9, resin strength will fall and the nonconformity of the heat expansion coefficient of each constituent material will increase markedly, possibly causing cracks in the package, severed bonding wires, and the like. For this reason, please inquire with us about whether this use is possible.

7. Cleaning solvents compatibility

We recommend cleaning with an organic solvent. If you cannot avoid using ultrasonic cleansing, please ensure that the following conditions are met, and check beforehand for defects.

• Frequency: 27 to 29 kHz

• Ultrasonic output:

No greater than 0.25W/cm²

• Cleaning time:

No longer than 30 s

• Cleanser used: Asahiklin AK-225

• Other:

Submerge in solvent in order to prevent the PCB and elements from being contacted directly by the ultrasonic vibrations.

Note: Applies to unit area ultrasonic output for ultrasonic baths.

8. Transportation

Extreme vibration during transport will warp the lead or damage the sensor. Handle the outer and inner boxes with care.

9. Avoid using the sensor in environments containing excessive amounts of steam, dust, corrosive gas, or where organic solvents are present.

Light Sensor (AMS1)

10. The following shows the packaging format

1) Tape and reel

mm inch

Type	Tape dimensions	Dimensions of paper tape reel
Light sensor	<p>(1) When picked from 1 and 4-pin side: Part No. AMS104Y (Shown above) (2) When picked from 2 and 3-pin side: Part No. AMS104W</p>	

NaPiCa light sensor terminology

Term	Symbol	Explanation
Reverse voltage	V_R	The applied voltage between the cathode and anode.
Photocurrent	I_L	The current that flows between the cathode and anode when light is applied.
Power dissipation	P	The electric power loss that occurs between the cathode and anode.
Operating temperature	T_{opr}	The workable ambient temperature range at which normal operation is possible under the condition of a prescribed allowable loss.
Storage temperature	T_{stg}	The ambient temperature range at which the sensor can be left or stored without applying voltage.
Peak sensitivity wavelength	λ_p	The wavelength of light at which sensitivity is at its maximum.
Dark current	I_D	The current between the cathode and anode when reverse voltage is applied during darkness.
Rise time	t_r	Time required for the output waveform to rise from 10% to 90% when light is applied.
Fall time	t_f	Time required for output waveform to lower from 90% to 10% when light is cut.